INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Mar 04 IC24 Data Handbook 1998 May 29



HILIPS

74LV367

FEATURES

- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- Typical V_{OLP} (output ground bounce) < 0.8V @ V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Typical V_OHV (output V_OH undershoot) > 2V @ V_CC = 3.3V, $T_{amb} = 25^{\circ}C$
- Non-inverting outputs
- Output capability: bus driver
- I_{CC} category: MSI

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

DESCRIPTION

The 74LV367 is a low-voltage CMOS device and is pin and function compatible 74HC/HCT367.

The 74LV367 is a hex non-inverting buffer/line driver with 3-State outputs. The 3-State outputs (nY) are controlled by the output enable inputs $(1\overline{OE}, 2\overline{OE})$.

A HIGH on $n\overline{OE}$, causes the outputs to assume a high impedance OFF-state.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA to nY	$C_L = 15pF$ $V_{CC} = 3.3V$	8	ns
Cl	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per buffer	Notes 1 and 2	30	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in $\mu W)$ P_D = C_{PD} × V_{CC}² × f_i + Σ (C_L × V_{CC}² × f_o) where: f_i = input frequency in MHz; C_L = output load capacitance in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V; Σ (C_L × V_{CC}² × f_o) = sum of the outputs. 2. The condition is V_I = GND to V_{CC}

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	–40°C to +125°C	74LV367 N	74LV367 N	SOT38-4
16-Pin Plastic SO	–40°C to +125°C	74LV367 D	74LV367 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV367 DB	74LV367 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV367 PW	74LV367PW DH	SOT403-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 15	10E, 20E	Output enable inputs (active-LOW)
2, 4, 6, 10, 12, 14	1A to 6A	Data inputs
3, 5, 7, 9, 11, 13	1Y to 6Y	Data outputs
8	GND	Ground (0V)
16	V _{CC}	Positive supply voltage

FUNCTION TABLE

INP	UTS	OUTPUT
nOE	nA	nY
L	L	L
L	Н	н
Н	Х	Z

H = HIGH voltage level

L = LOW voltage level

X = Don't care

Z = High impedance OFF-state

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PIN CONFIGURATION



LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	3.6	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times				500 200 100	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 3.6V.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
±I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 V$	20	mA
±I _{OK}	DC output diode current	$V_{\rm O}$ < –0.5 or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5V	50	mA
±IO	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with -bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{tot}	Power dissipation per package –plastic DIL –plastic mini-pack (SO) –plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8	5°C	-40°C to	o +125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	
		$V_{CC} = 1.2V$	0.9			0.9		
VIH	HIGH level Input voltage	$V_{CC} = 2.0 V$	1.4			1.4		V
		V _{CC} = 2.7 to 3.6V	2.0			2.0		
		$V_{CC} = 1.2V$			0.3		0.3	
VIL	LOW level Input voltage	$V_{CC} = 2.0 V$			0.6		0.6	V
		V _{CC} = 2.7 to 3.6V			0.8		0.8	
		V_{CC} = 1.2V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μA		1.2				
	HIGH level output	V_{CC} = 2.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	1.8	2.0		1.8		v
V _{OH}	voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	2.5	2.7		2.5] `
		V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	2.8	3.0		2.8		
V _{OH}	HIGH level output voltage; BUS driver outputs	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 8mA$	2.40	2.82		2.20		V
		V_{CC} = 1.2V; V_I = V_{IH} or $V_{IL;}$ I_O = 100 μA		0				
V _{OL}	LOW level output	V_{CC} = 2.0V; V_I = V_{IH} or $V_{IL;}$ I_O = 100 μA		0	0.2		0.2	
VOL	voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or $V_{IL;} I_O$ = 100 μ A		0	0.2		0.2	Ì
		V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;} I_O$ = 100 μ A		0	0.2		0.2]
V _{OL}	LOW level output voltage; BUS driver outputs	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 8mA$		0.20	0.40		0.50	V
lı	Input leakage current	V_{CC} = 3.6V; V_{I} = V_{CC} or GND			1.0		1.0	μΑ
I _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or } GND$			5		10	μΑ
Icc	Quiescent supply current; MSI	V_{CC} = 3.6V; V_{I} = V_{CC} or GND; I_{O} = 0			20.0		160	μΑ
ΔI _{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$			500		850	μΑ

NOTE:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

Product specification

AC CHARACTERISTICS

GND = 0V; $t_r = t_f \le 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 1 \text{K}\Omega$

			CONDITION			LIMITS							
SYMBOL	PARAMETER	WAVEFORM	CONDITION		40 to +85 °	С	-40 to -	+125 °C	UNIT				
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX					
			1.2	-	50	-	-	-					
••	Propagation delay	Figure 1	2.0	-	17	32	-	39	20				
t _{PHL} /t _{PLH}	nA to nY	Figure i	2.7	-	13	24	-	29	ns				
							3.0 to 3.6	-	10 ²	19	-	23	
				1.2	-	80	-	-	-				
	3-State output enable time	Figure 2	2.0	-	27	51	-	60					
t _{PZH} /t _{PZL}	nOE to nY	Figure 2	2.7	-	20	38	-	44	ns				
			3.0 to 3.6	-	15 ²	30	-	36					
			1.2	-	90	-	-	-					
	3-State output	Figure 0	2.0	-	32	59	-	70	~~				
t _{PHZ} /t _{PLZ}	nOE to nY	isable time Figure 2 OE to nY	2.7	-	24	44	-	52	ns				
			3.0 to 3.6	-	19 ²	36	-	42					

NOTES:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$ 2. Typical values are measured at $V_{CC} = 3.3V$

AC WAVEFORMS

 V_M = 1.5V at $V_{CC} \ge 2.7V$ V_M = 0.5V * V_{CC} at $V_{CC} < 2.7V$ $V_{\mbox{OL}}$ and $V_{\mbox{OH}}$ are the typical output voltage drop that occur with the output load. $V_X = V_{OL} + 0.3V$ at $V_{CC} \ge 2.7V$ $\begin{array}{l} V_X = V_{OL} \ 0.1V_{CC} \ at \ V_{CC} < 2.7V \\ V_Y = V_{OH} - 0.3V \ at \ V_{CC} \geq 2.7V \\ V_Y = V_{OH} - 0.3V \ at \ V_{CC} \geq 2.7V \\ V_Y = V_{OH} - 0.1V_{CC} \ at \ V_{CC} < 2.7V \end{array}$



Figure 1. Input (nA) to output (nY) propagation delays.



Figure 2. 3-State enable and disable times.

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TEST CIRCUIT



Figure 3. Load circuitry for switching times.

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DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	с	D ⁽¹⁾	Е ⁽¹⁾	е	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	IEC JEDEC EIAJ			PROJECTION	ISSUE DATE	
SOT38-4						-92-11-17 95-01-14	







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	DEFINITIONS							
Data Sheet Identification Product Status Definition		Definition						
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.						
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